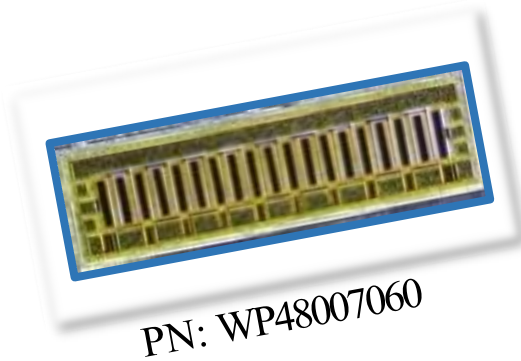




WP48007060

60W, 48V GaN HEMT Die



PN: WP48007060

The WP48007060 is a 60W gallium nitride (GaN) High Electron Mobility Transistor (HEMT). This GaN HEMT is a wideband transistor optimized for 5.8GHz operation in a user-friendly device for high bandwidth applications. Gallium nitride (GaN) HEMT is a device optimized for 5G. GaN HEMT resistance is only 1/10 that of silicon transistors, making it capable of switching frequencies faster for greater energy efficiency.

Features

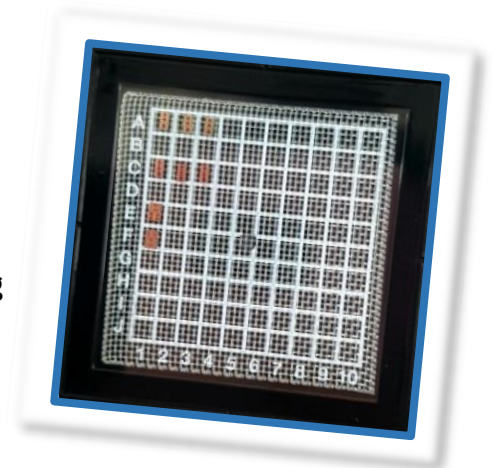
- Up to 8 GHz Operation
- 14.0 dB Typical Small Signal Gain @ 3.5 GHz
- 60 W Typical Psat @5.8GHz
- 48V Operation
- High Breakdown Voltage
- High Breakdown Voltage
- High Efficiency
- Reliability Monitoring Supporting

Applications

- U/VHF Amplifiers
- Broadband Amplifiers
- Base Station Communications
- Drone, UAV
- WiMAX, LTE, WCDMA, GSM
- WPT, V2X
- Radar application

Packaging Information

- Bare die are shipped in Wafer-level with Expander Ring or Gel-Pak® containers.
- Possible UV Curing for Wafer-level with dicing saw



Absolute Maximum Ratings (not simultaneous) at 25 °C

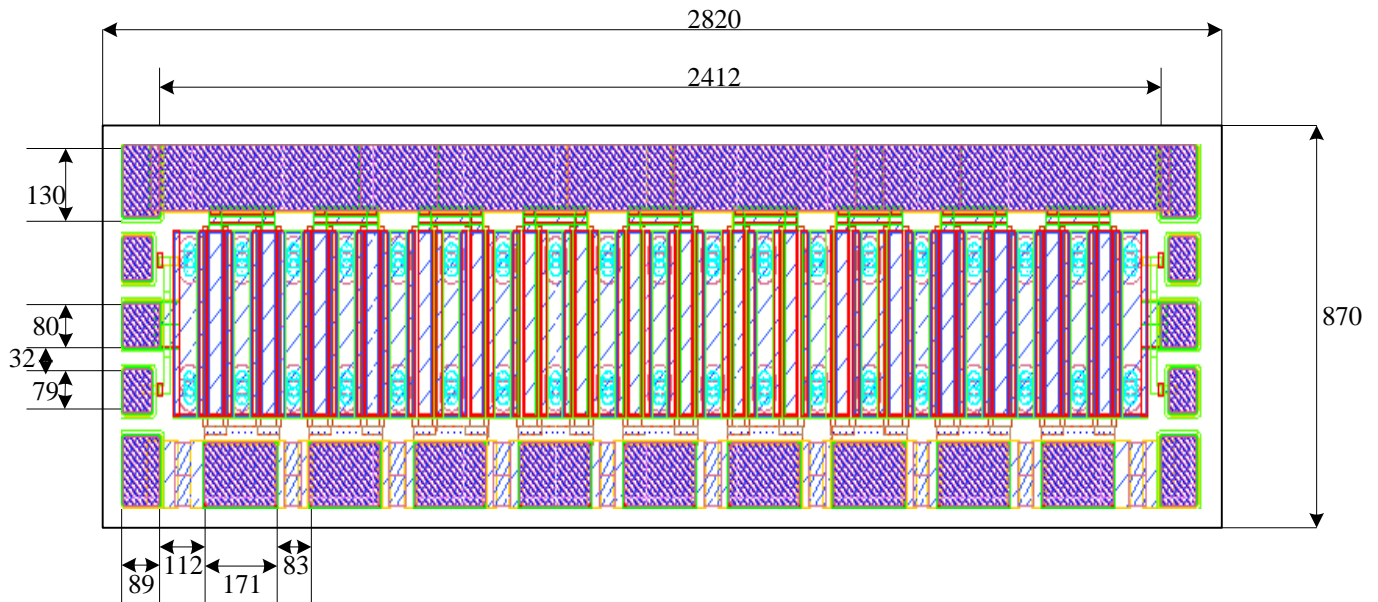
| Parameter | Parameter | Typical Value | Units | Conditions |
|---|------------------|---------------|-------|------------|
| Threshold voltage @ Id=1mA/mm, Vd=10V | V _{to} | -3.4 | V | 25°C |
| Breakdown voltage @ Id=1mA/mm | V _{DG} | 160 | V | 25°C |
| Drain-source current, Id @ Vd=10V, Vg=0 | I _{dss} | 800 | mA/mm | 25°C |
| Operating Junction Temperature | T _J | 225 | °C | |
| Storage Temperature | T _{STG} | -65, +150 | °C | |
| Thermal Resistance, Junction to Case (packaged) | R _{θJC} | | °C/W | |
| Thermal Resistance, Junction to Case (die only) | R _{θJC} | | °C/W | |
| Mounting Temperature (30 seconds) | T _S | 320 | °C | 30 seconds |

Electrical Characteristics (Frequency = 3.5 GHz unless otherwise stated; TC = 25 °C)

| Parameter | Parameter | Typical Value | Units | Conditions |
|---|-------------------|---------------|--------|--|
| DC Characteristics | | | | |
| Ohmic contact resistance | RC | 0.3 | Ohm-mm | 25°C |
| Maximum Drain-source current, Id @ Vd=10V, Vg=1V (1X125µm device) | I _{dmax} | 1000 | mA/mm | 25°C |
| Max. trans-conductance, @ Vd=10V, Vg=-4V ~ -1V (1X125µm device) | GM_PEAK | 290 | mS/mm | 25°C |
| Maximum Drain-source current, Id @ Vd=10V, Vg=1V (1X125µm device) | I _{dmax} | 1000 | mA/mm | 25°C |
| RF Characteristics | | | | |
| Small Signal Gain | G _{SS} | >12 | dB | V _{DD} =48V, I _{DQ} =400mA |
| Saturated Power Output | P _{SAT} | 60 | W | V _{DD} =48V, I _{DQ} =400mA |
| Drain Efficiency | η | >60 | % | V _{DD} =48V, I _{DQ} =400mA |
| Intermodulation Distortion | IM3 | <-30 | dBc | V _{DD} =48V, I _{DQ} =400mA |
| Output Mismatch Stress | VSWR | 10:1 | ψ | |



DIE Dimensions (units in microns)



Overall die size 2820 x 870 (+0/-50) microns, die thickness 100 (+/- 10) microns.
All Gate and Drain pads must be wire bonded for electrical connection.

Assembly Notes:

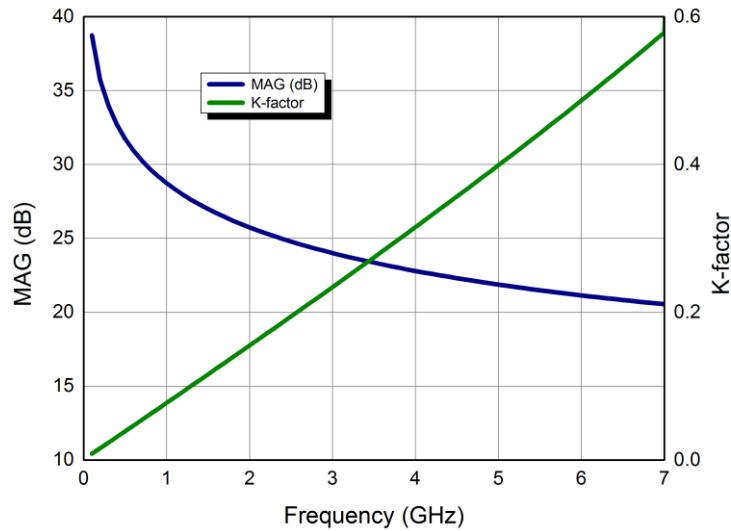
- Recommended solder is AuSn (80/20) solder. Refer to Wavepia's guide for the Eutectic Die Bond Procedure
- Vacuum collet is the preferred method of pick-up.
- The backside of the die is the Source (ground) contact.
- Die back side gold plating is 5 microns thick minimum.
- Thermosonic ball or wedge bonding are the preferred connection methods.
- Gold wire must be used for connections.



Typical Performance

Simulated Maximum Available Gain (MAG) and K Factor of the WP48007060

$V_{DD} = 48 \text{ V}$, $I_{DQ} = 400 \text{ mA}$

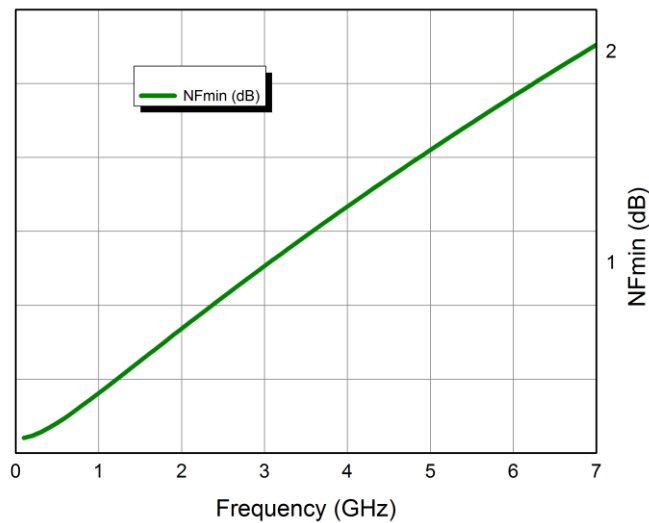


Intrinsic die parameters - reference planes at centers of gate and drain bonding pads. No wire bonds assumed.

Typical Performance

Simulated Minimum Noise Figure of the WP48007060

$V_{DD} = 48 \text{ V}$, $I_{DQ} = 400 \text{ mA}$





Typical Die S-Parameters

(Small Signal, $V_{DS} = 48\text{ V}$, $I_{DQ} = 400\text{ mA}$, magnitude / angle)

| Frequency | Mag S11 | Ang S11 | Mag S21 | Ang S21 | Mag S12 | Ang S12 | Mag S22 | Ang S22 |
|-----------|----------|----------|----------|----------|----------|----------|----------|----------|
| 100MHz | 0.966949 | -95.9509 | 59.69612 | 129.7508 | 0.007997 | 39.8653 | 0.456755 | -144.412 |
| 200MHz | 0.951199 | -131.409 | 36.29644 | 110.8004 | 0.009725 | 21.02931 | 0.55401 | -157.929 |
| 300MHz | 0.946515 | -146.415 | 25.32035 | 102.0381 | 0.010175 | 12.38151 | 0.581258 | -163.394 |
| 400MHz | 0.94478 | -154.402 | 19.28884 | 96.72547 | 0.010335 | 7.183379 | 0.593117 | -165.962 |
| 500MHz | 0.944082 | -159.305 | 15.52312 | 92.92516 | 0.010395 | 3.497567 | 0.6003 | -167.255 |
| 600MHz | 0.94385 | -162.601 | 12.95828 | 89.9145 | 0.010412 | 0.601406 | 0.605827 | -167.894 |
| 700MHz | 0.943869 | -164.96 | 11.10095 | 87.36825 | 0.010404 | -1.83033 | 0.610777 | -168.164 |
| 800MHz | 0.944046 | -166.727 | 9.693934 | 85.11983 | 0.010382 | -3.96423 | 0.6156 | -168.211 |
| 900MHz | 0.944331 | -168.097 | 8.590728 | 83.07561 | 0.010348 | -5.89392 | 0.620501 | -168.122 |
| 1000MHz | 0.9447 | -169.188 | 7.701989 | 81.17918 | 0.010306 | -7.67579 | 0.62557 | -167.947 |
| 1100MHz | 0.945135 | -170.075 | 6.970224 | 79.39473 | 0.010257 | -9.34567 | 0.630847 | -167.721 |
| 1200MHz | 0.945624 | -170.81 | 6.356803 | 77.6985 | 0.010202 | -10.9273 | 0.636341 | -167.465 |
| 1300MHz | 0.94616 | -171.429 | 5.834826 | 76.07421 | 0.010141 | -12.437 | 0.642046 | -167.196 |
| 1400MHz | 0.946736 | -171.956 | 5.384994 | 74.51038 | 0.010076 | -13.8862 | 0.647945 | -166.924 |
| 1500MHz | 0.947347 | -172.41 | 4.993105 | 72.99871 | 0.010007 | -15.2832 | 0.654019 | -166.658 |
| 1600MHz | 0.947988 | -172.806 | 4.648479 | 71.53307 | 0.009933 | -16.6341 | 0.660243 | -166.402 |
| 1700MHz | 0.948655 | -173.154 | 4.342932 | 70.10887 | 0.009857 | -17.9436 | 0.666593 | -166.161 |
| 1800MHz | 0.949344 | -173.463 | 4.070084 | 68.72257 | 0.009777 | -19.2152 | 0.673043 | -165.938 |
| 1900MHz | 0.950052 | -173.738 | 3.824892 | 67.37142 | 0.009694 | -20.4516 | 0.67957 | -165.734 |
| 2000MHz | 0.950775 | -173.986 | 3.603312 | 66.05326 | 0.009608 | -21.6549 | 0.68615 | -165.549 |
| 2100MHz | 0.951511 | -174.211 | 3.402067 | 64.76633 | 0.00952 | -22.827 | 0.69276 | -165.385 |
| 2200MHz | 0.952257 | -174.415 | 3.21847 | 63.50918 | 0.009431 | -23.9693 | 0.699379 | -165.241 |
| 2300MHz | 0.95301 | -174.603 | 3.050299 | 62.2806 | 0.009339 | -25.0829 | 0.705989 | -165.118 |
| 2400MHz | 0.953768 | -174.776 | 2.895695 | 61.07957 | 0.009246 | -26.169 | 0.712571 | -165.014 |
| 2500MHz | 0.954528 | -174.936 | 2.753096 | 59.90518 | 0.009151 | -27.2284 | 0.71911 | -164.929 |
| 2600MHz | 0.955289 | -175.085 | 2.621176 | 58.75665 | 0.009056 | -28.2618 | 0.725592 | -164.863 |
| 2700MHz | 0.956049 | -175.225 | 2.498801 | 57.63324 | 0.008959 | -29.2702 | 0.732003 | -164.813 |
| 2800MHz | 0.956806 | -175.356 | 2.384998 | 56.5343 | 0.008862 | -30.2539 | 0.738332 | -164.78 |
| 2900MHz | 0.957558 | -175.479 | 2.278923 | 55.45921 | 0.008764 | -31.2138 | 0.74457 | -164.762 |
| 3000MHz | 0.958304 | -175.596 | 2.179845 | 54.40739 | 0.008666 | -32.1504 | 0.750708 | -164.758 |
| 3100MHz | 0.959043 | -175.707 | 2.08712 | 53.37828 | 0.008568 | -33.0642 | 0.756739 | -164.768 |
| 3200MHz | 0.959774 | -175.813 | 2.000187 | 52.37134 | 0.008469 | -33.9558 | 0.762657 | -164.79 |
| 3300MHz | 0.960496 | -175.914 | 1.918547 | 51.38605 | 0.008371 | -34.8256 | 0.768457 | -164.823 |
| 3400MHz | 0.961207 | -176.011 | 1.841759 | 50.4219 | 0.008273 | -35.6743 | 0.774135 | -164.867 |
| 3500MHz | 0.961908 | -176.104 | 1.769431 | 49.47841 | 0.008175 | -36.5022 | 0.779688 | -164.921 |
| 3600MHz | 0.962597 | -176.194 | 1.701211 | 48.55506 | 0.008077 | -37.31 | 0.785114 | -164.983 |
| 3700MHz | 0.963274 | -176.28 | 1.636785 | 47.6514 | 0.00798 | -38.0979 | 0.790412 | -165.053 |
| 3800MHz | 0.963939 | -176.363 | 1.575868 | 46.76694 | 0.007883 | -38.8667 | 0.79558 | -165.131 |
| 3900MHz | 0.964591 | -176.444 | 1.518205 | 45.90122 | 0.007787 | -39.6166 | 0.800618 | -165.215 |

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